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Journal articles

[1] Shunin Yu N, Zhukovskii Yu F, Gopejenko V I, Burlutskaya N, Lobanova-Shunina T, Bellucci S 2012 *Journal of Nanophotonics* **6**(1) 31-6

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Figure

FIGURE 1 Figure title

Figure

FIGURE 2 Figure title

Figure

FIGURE 3 Figure title

TABLE 1 Table title

Column title	Column title	Column title
Text	Text	Text
Text	Text	Text

$$\breve{S}_\alpha(t,M) = \sum_{k=1}^{M} \left(\breve{a}_k \sin(\breve{x}_k t) X_k + \breve{b}_k (1 - \cos(\breve{y}_k t)) Y_k \right) \tag{1}$$

2.2.1 A subsubsection.
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3 Conclusions

Acknowledgements

Appendix A Appendix title

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